

## N-Channel Power MOSFET

600V, 2.3A, 4.4Ω

### FEATURES

- 100% UIS and R<sub>g</sub> tested
- Pb-free plating
- RoHS compliant
- Halogen-free according to IEC 61249-2-21

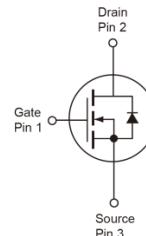
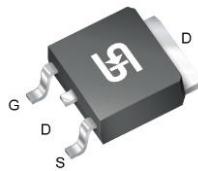
PRODUCT SUMMARY			
PARAMETER	VALUE	UNIT	
V <sub>DS</sub>	600	V	
R <sub>DS(on)</sub> (max)	V <sub>GS</sub> = 10V	4.4	Ω
Q <sub>g</sub>	V <sub>GS</sub> = 10V	9.9	nC

### APPLICATIONS

- Lighting
- Charger
- Power Supply
- Switching applications



TO-252 (DPAK)



Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V <sub>DS</sub>	600	V	
Gate-Source Voltage	V <sub>GS</sub>	±30	V	
Continuous Drain Current	T <sub>C</sub> = 25°C	2.3	A	
	T <sub>C</sub> = 100°C	1.5		
	T <sub>A</sub> = 25°C	0.4		
Pulsed Drain Current <sup>(Note 1)</sup>	I <sub>DM</sub>	9.2	A	
Single Pulse Avalanche Current <sup>(Note 2)</sup>	I <sub>AS</sub>	3.3	A	
Single Pulse Avalanche Energy <sup>(Note 2)</sup>	E <sub>AS</sub>	55	mJ	
Total Power Dissipation	T <sub>C</sub> = 25°C	P <sub>D</sub>	62	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C	

### THERMAL RESISTANCE

PARAMETER	SYMBOL	MAXIMUM	UNIT
Thermal Resistance – Junction to Case	R <sub>θJC</sub>	2	°C/W
Thermal Resistance – Junction to Ambient	R <sub>θJA</sub>	62	°C/W

**Note:** R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. R<sub>θJA</sub> is guaranteed by design while R<sub>θCA</sub> is determined by the user's board design. R<sub>θJA</sub> shown below for single device operation on FR-4 PCB with minimum recommended footprint in still air.

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25^\circ C$ unless otherwise noted)						
<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	$BV_{DSS}$	600	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu A$	$V_{GS(TH)}$	2.5	2.9	4.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 100$	nA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = 600V$	$I_{DSS}$	--	--	10	$\mu A$
Drain-Source On-State Resistance <small>(Note 3)</small>	$V_{GS} = 10V, I_D = 1A$	$R_{DS(on)}$	--	3.9	4.4	$\Omega$
Forward Transfer Conductance	$V_{DS} = 10V, I_D = 1A$	$g_{fs}$	--	2.8	--	S
<b>Dynamic</b>						
Total Gate Charge	$V_{GS} = 10V, V_{DS} = 480V, I_D = 2A$	$Q_g$	--	9.9	--	nC
Gate-Source Charge		$Q_{gs}$	--	1.5	--	
Gate-Drain Charge		$Q_{gd}$	--	4.7	--	
Input Capacitance	$V_{GS} = 0V, V_{DS} = 25V, f = 1.0MHz$	$C_{iss}$	--	316	--	pF
Output Capacitance		$C_{oss}$	--	32	--	
Reverse Transfer Capacitance		$C_{rss}$	--	1	--	
Gate Resistance	$f = 1.0MHz$	$R_g$	--	2.8	--	$\Omega$
<b>Switching</b> <small>(Note 4)</small>						
Turn-On Delay Time	$V_{GS} = 10V, V_{DS} = 300V, I_D = 2A, R_G = 25\Omega$	$t_{d(on)}$	--	7.3	--	ns
Rise Time		$t_r$	--	9.6	--	
Turn-Off Delay Time		$t_{d(off)}$	--	23	--	
Fall Time		$t_f$	--	18	--	
<b>Source-Drain Diode</b>						
Diode Forward Voltage <small>(Note 3)</small>	$V_{GS} = 0V, I_S = 2A$	$V_{SD}$	--	0.8	1.4	V
Source Current	Integral reverse diode In the MOSFET	$I_S$	--	--	2.3	A
Source Current (Pulse)		$I_{SM}$	--	--	9.2	

**Notes:**

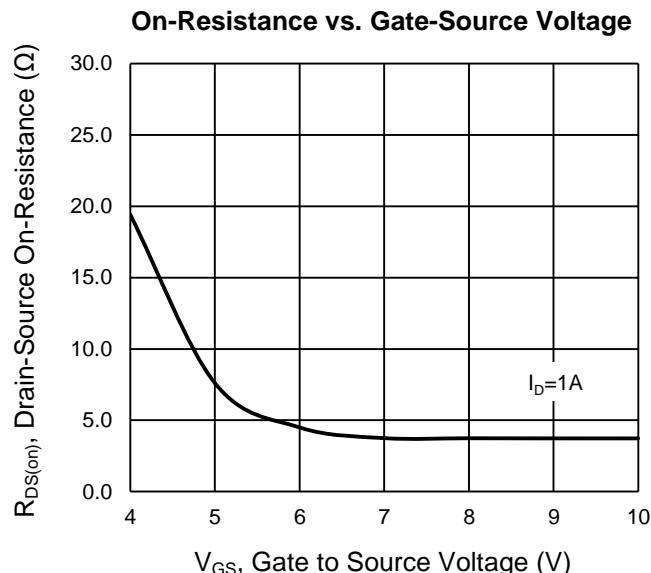
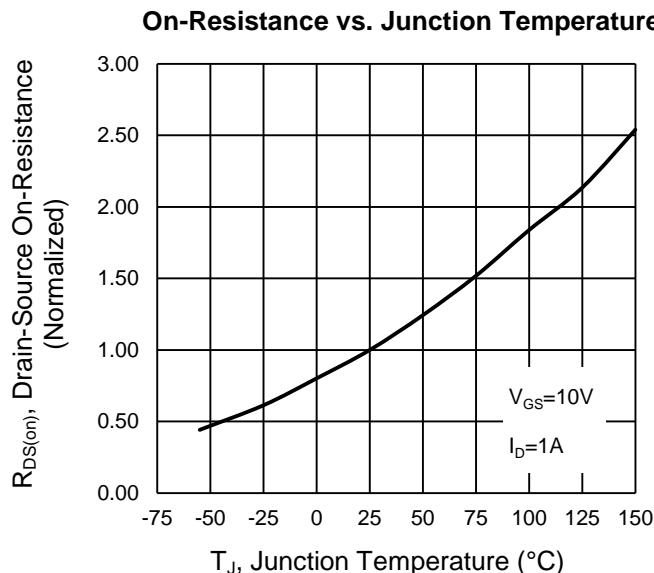
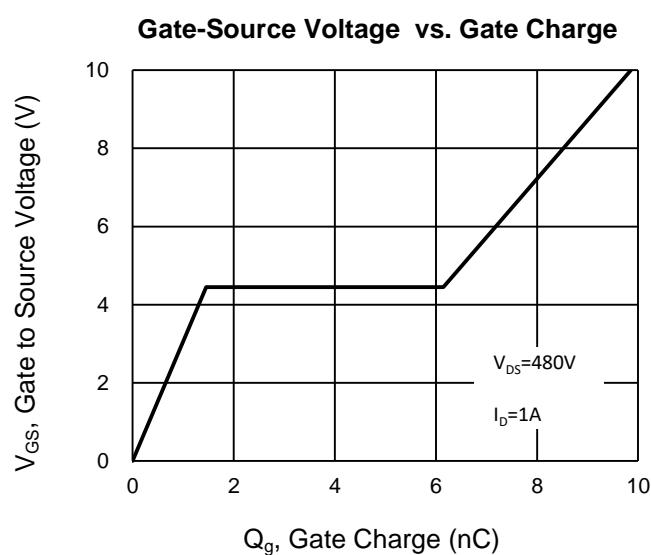
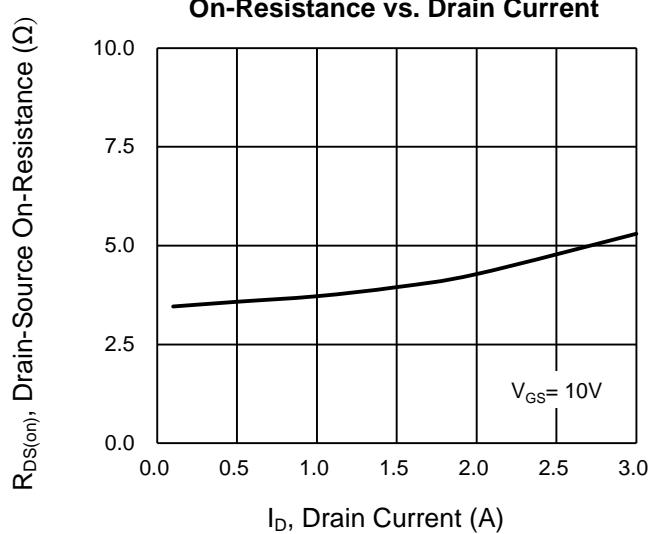
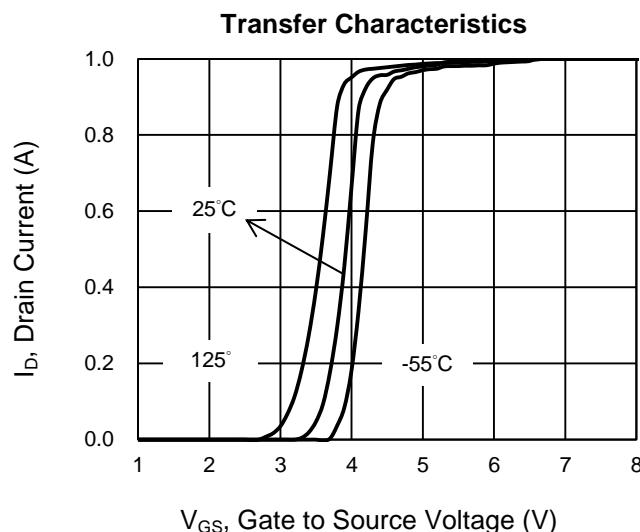
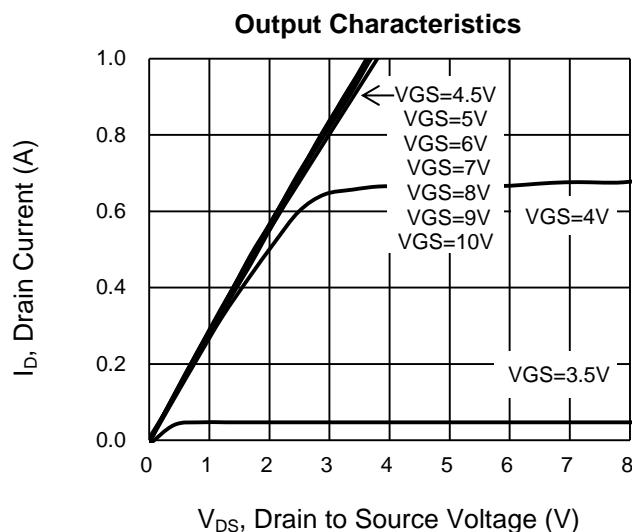
1. Pulsed width limited by maximum junction temperature.
2.  $L = 10mH, V_{GS} = 10V, R_G = 25\Omega$ , Starting  $T_J = 25^\circ C$ .
3. Pulse test: Pulse Width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
4. Switching time is essentially independent of operating temperature.

**ORDERING INFORMATION**

<b>ORDERING CODE</b>	<b>PACKAGE</b>	<b>PACKING</b>
TSM2NB60CP ROG	TO-252 (DPAK)	2,500 pcs / 13" Reel

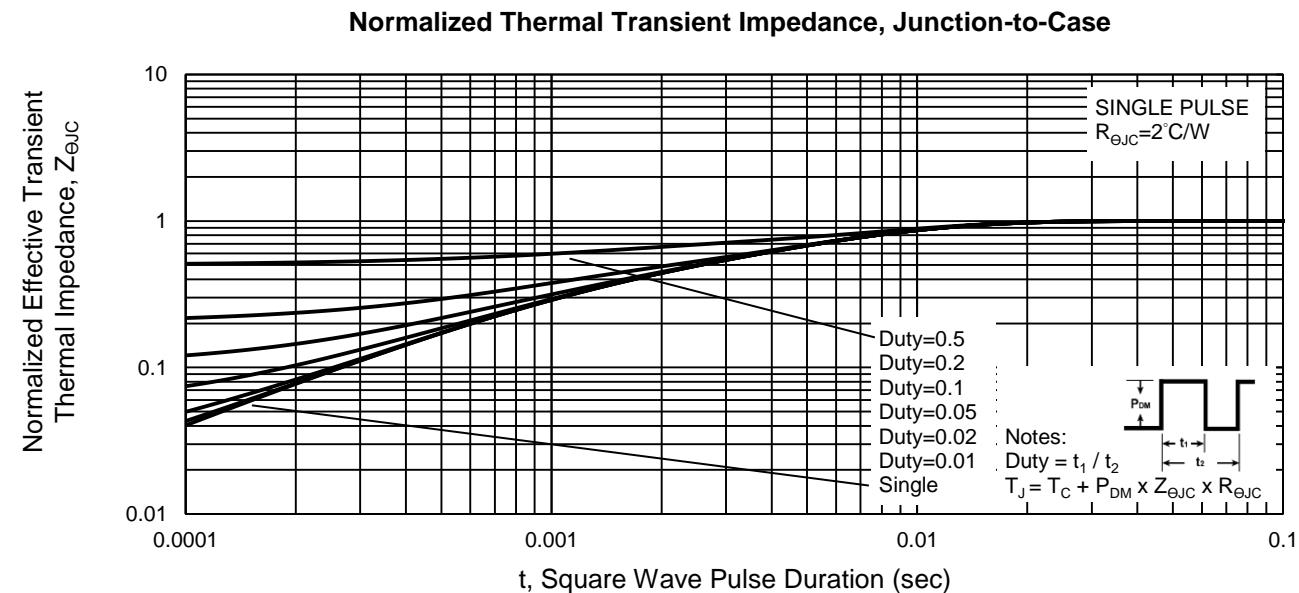
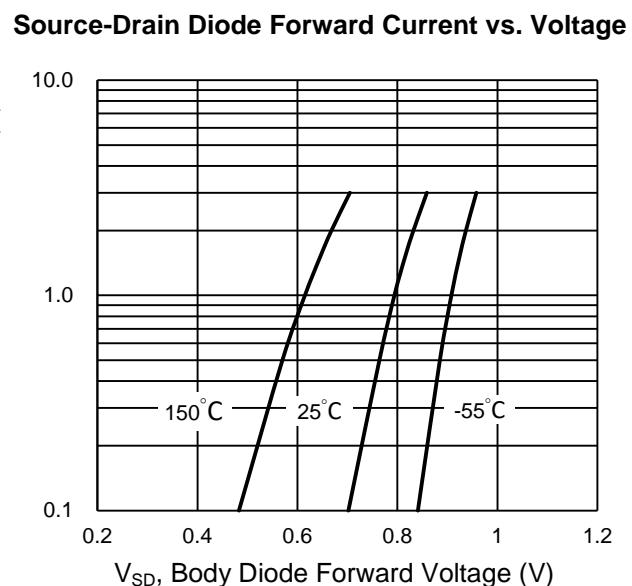
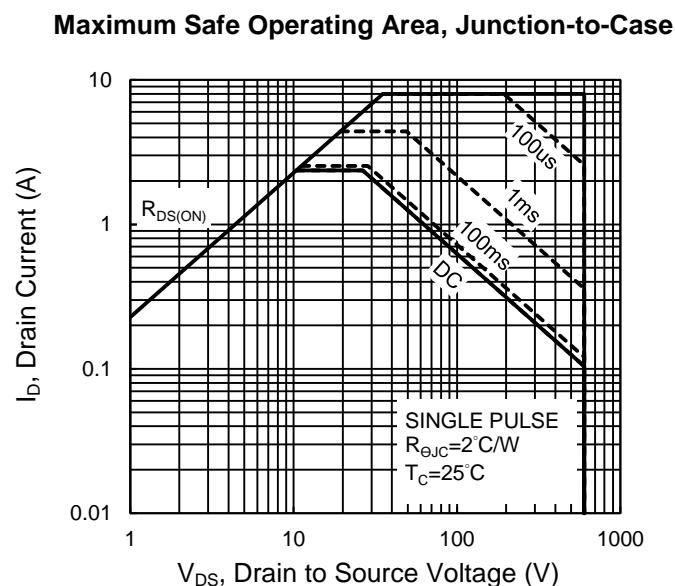
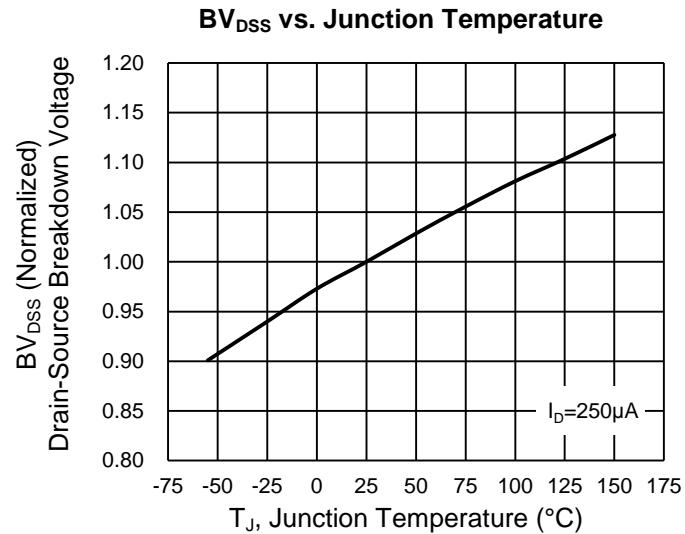
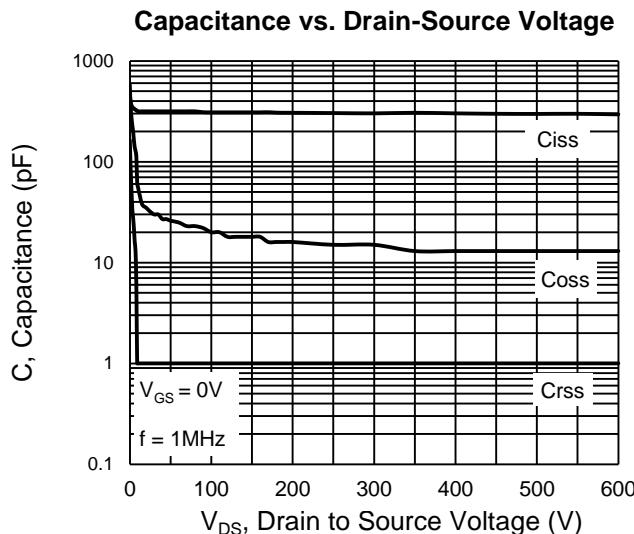
## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)



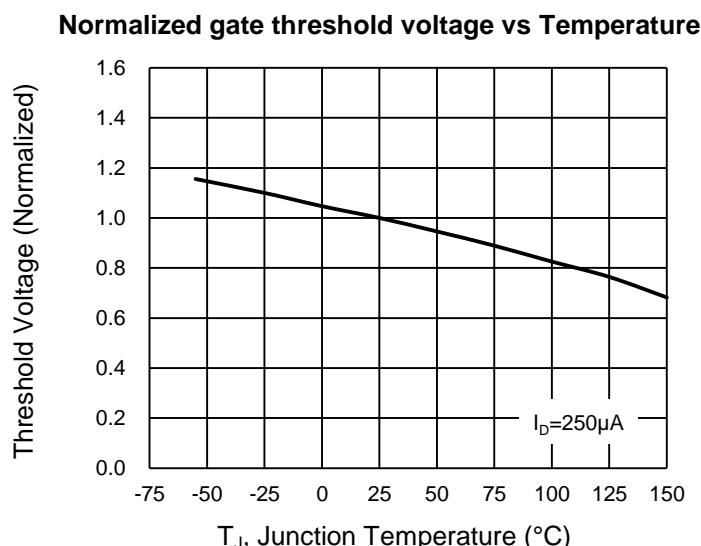
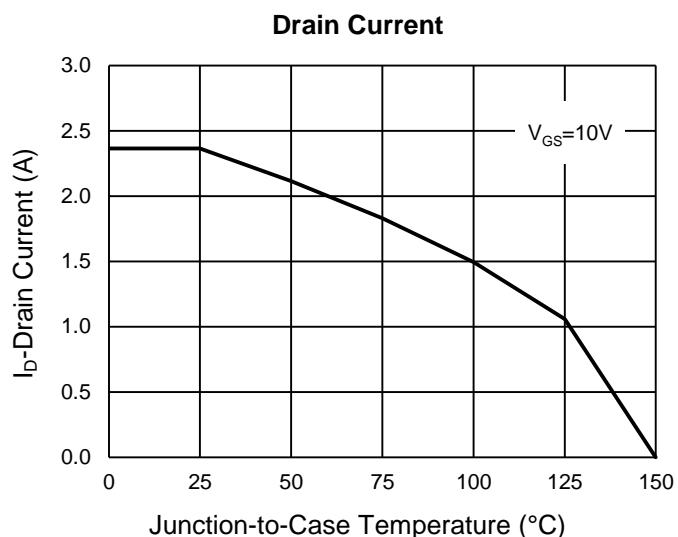
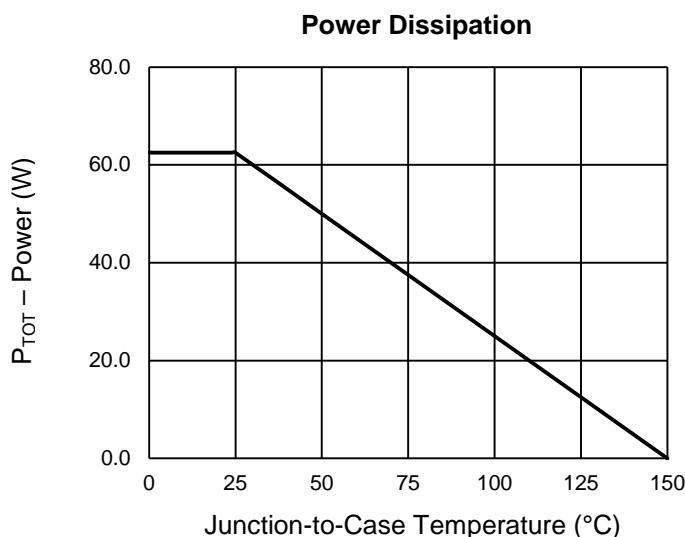
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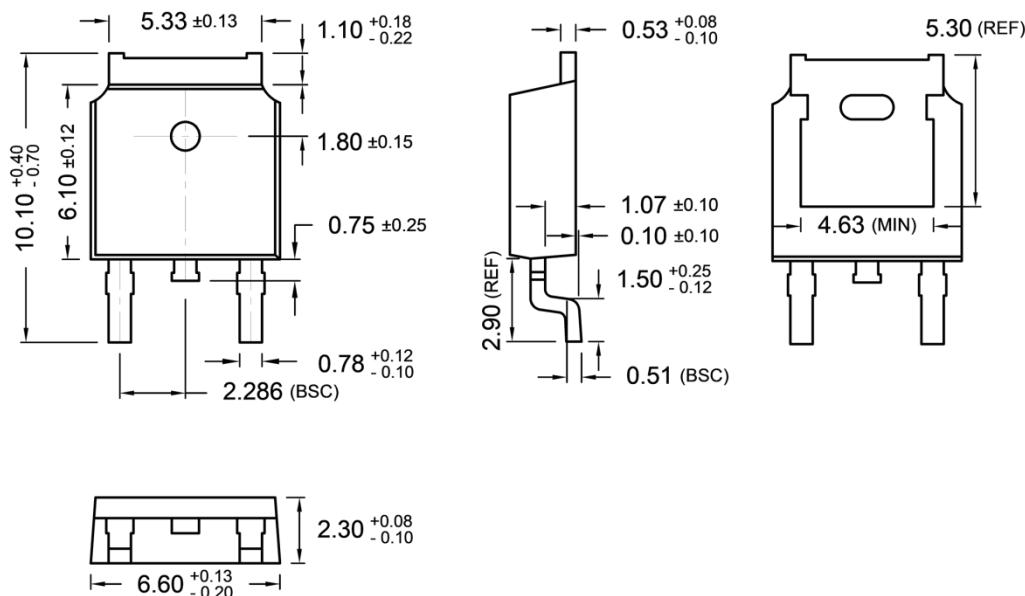
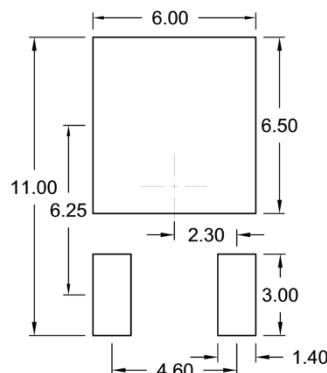


## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)



**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)

**TO-252 (DPAK)**

**SUGGESTED PAD LAYOUT** (Unit: Millimeters)

**MARKING DIAGRAM**

**Y** = Year Code

**M** = Month Code

**O** =Jan   **P** =Feb   **Q** =Mar   **R** =Apr

**S** =May   **T** =Jun   **U** =Jul   **V** =Aug

**W** =Sep   **X** =Oct   **Y** =Nov   **Z** =Dec

**L** = Lot Code (1~9, A~Z)

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